Ultrafast Rectifier

30 A, 600 V

RURG3060-F085

Description

The RURG3060–F085 is an ultrafast diode with soft recovery characteristics (trr< 80 ns). It has low forward voltage drop and is silicon nitride passivated ion–implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Features

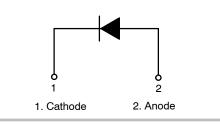
- High Speed Switching ($t_{rr} = 60 \text{ ns}(\text{Typ.}) @ I_F = 30 \text{ A}$)
- Low Forward Voltage ($V_F = 1.5 \text{ V(Max.)} @ I_F = 30 \text{ A}$)
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- This Device is Pb–Free

Applications

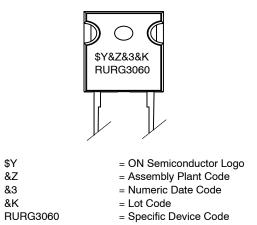
- Automotive DC/DC Converter
- Automotive On Board Charger
- Switching Power Supply
- Power Switching Circuits







MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage		600	V
Working Peak Reverse Voltage	V _{RWM}	600	V
DC Blocking Voltage		600	V
Average Rectified Forward Current ($T_C = 25^{\circ}C$)		30	А
Non-repetitive Peak Surge Current (Halfwave 1 Phase 50 Hz)		90	А
Avalanche Energy (1 A, 40 mH)		20	mJ
Operating Junction and Storage Temperature	T _{J,} T _{STG}	–55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Tube	Quantity
RURG3060-F085	RURG3060	TO-247-2LD	-	30

THERMAL CHARACTERISTICS (T_C = 25° C unless otherwise noted)

Parameter		Value	Unit
Maximum Thermal Resistance, Junction to Case		0.7	°C/W
Maximum Thermal Resistance, Junction to Ambient		45	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

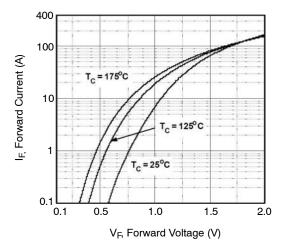
Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
Instantaneous Reverse Current	I _R	V _R = 600 V	$T_{C} = 25^{\circ}C$	-	-	250	μA
			T _C = 175°C	-	-	1	mA
Instantaneous Forward Voltage (Note 1)	V _{FM}	I _F = 30 A	$T_{C} = 25^{\circ}C$	-	1.26	1.5	V
			$T_{C} = 175^{\circ}C$	-	1.06	1.3	V
Reverse Recovery Time (Note 2)	t _{rr}	I _F = 1 A, di/dt =100 A/μs, V _{CC} = 390 V	$T_{\rm C} = 25^{\circ}{\rm C}$	-	35	55	ns
		I_F = 30 A, di/dt = 100 A/µs, V_{CC} = 390 V	$T_{C} = 25^{\circ}C$	-	60	80	ns
			T _C = 175°C	-	231	-	ns
Reverse Recovery Time	t _a	$I_{F} = 30 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s},$	$T_{C} = 25^{\circ}C$	-	31	-	ns
	t _b	V _{CC} = 390 V		-	29	-	ns
Reverse Recovery Charge	Q _{rr}			-	92	-	nC
Avalanche Energy	E _{AVL}	I _{AV} = 1.0 A, L = 40 mH	-	20	-	-	mJ

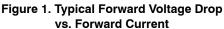
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse: Test Pulse Width = 300 µs, Duty Cycle = 2%

2. Guaranteed by design.

TYPICAL PERFORMANCE CHARACTERISTICS





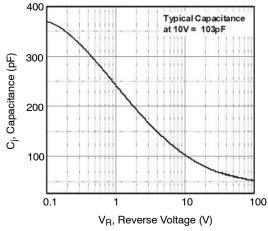


Figure 3. Typical Junction Capacitance

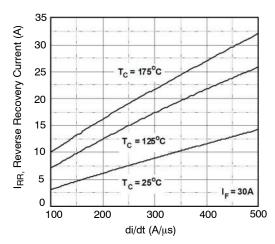


Figure 5. Typical Reverse Recovery Current vs. di/dt

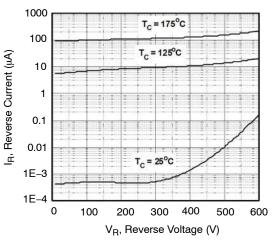


Figure 2. Typical Reverse Current vs. Reverse Voltage

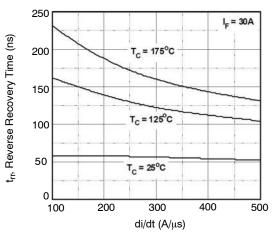
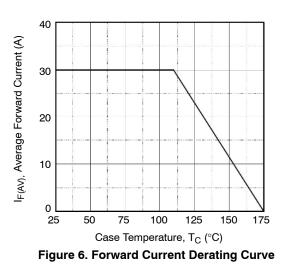


Figure 4. Typical Reverse Recovery Time vs. di/dt



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

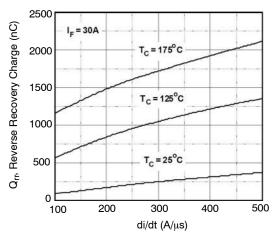
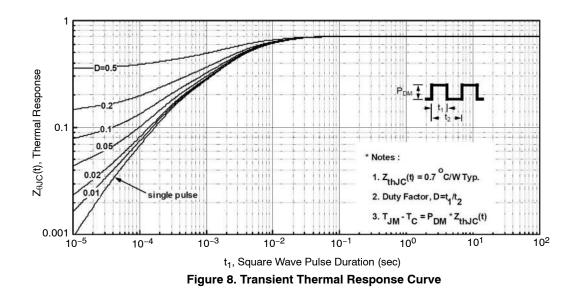
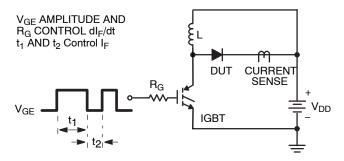


Figure 7. Reverse Recovery Charge



TEST CIRCUIT AND WAVEFORMS





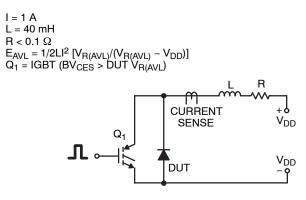


Figure 11. Avalanche Energy Test Circuit

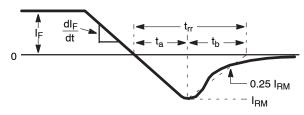


Figure 10. t_{rr} Waveforms and Definitions

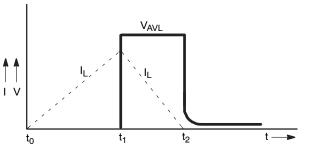


Figure 12. Avalanche Current and Voltage Waveforms

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MILLIMETERS

NOM

4.70

2.40

1.50

1.26

1.65

0.61

20.57

16.57

0.93

15.62

~

5.08

11.12

16.00

3.81

3.58

6.73

5.46

5.46

MAX

4.82

2.66

1.70

1.35

1.77

0.71

20.82

16.77

1.35

15.87

~

5.20

~

16.25

3.93

3.65

6.85

5.58

5.58

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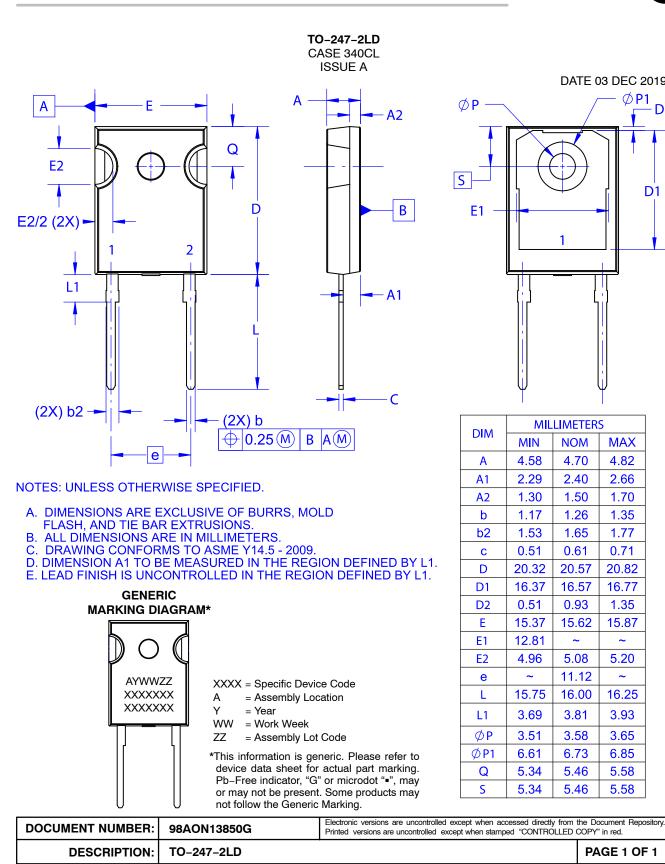
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